

Q-1 Answer the following MCQ's with correct option. (1 Mark each) (5)

- 1 A good biasing circuit should establish the operating point on a load line
(a) near saturation region (b) near cut-off region
(c) at middle of active region (d) outside active region
- 2 Which of the following h-parameter represents forward current gain of a CE transistor ?
(a) h_{fe} (b) h_{ie} (c) h_{re} (d) h_{oe}
- 3 The voltage gain of an emitter follower is
(a) less than 1 (b) greater than 1 (c) equal to 1 (d) none of above
- 4 The JFET is a device.
(a) bipolar (b) unipolar (c) tripolar (d) metaalic
- 5 The slope of a dc load of a CE amplifier with collector resistor R_C is equal to
(a) R_C (b) $1/R_C$ (c) $R_C/2$ (d) $2 R_C$



Answer the following questions. (5 Mark each)

- Q-2** With proper example explain determination of operating point of a Fixed bias circuit. (5)

OR

With proper example explain determination of operating point of Voltage divider biasing circuit using approximate analysis method.

- Q-3** Using equivalent circuit method, explain development of transistor equivalent circuit. (5)

OR

What are h parameters? Define them. Explain development of h-parameter equivalent circuit for CE transistor.

- Q-4** Explain how the negative feedback in an amplifier helps to:
(i) Stabilize the gain and (ii) Increase input impedance. (5)

OR

Write notes on: (i) Harley Oscillator and (ii) Colpitts Oscillator

- Q-5** Explain structure and basic operation of a JFET. Draw the drain curves and explain pinch-off voltage, ohmic resistance and gate-source cut-off voltage. (5)

OR

Discuss applications of JFET as (i) JFET Amplifiers and as (ii) an analog series and shunt switch.